

SANYO Semiconductors DATA SHEET

SB80W06T — Schottky Barrier Diode (Twin Type • Cathode Common) 60V, 8A Rectifier

Applications

• High frequency rectification (switching regulators, converters, choppers).

Features

- Low forward voltage (V_F max=0.6V).
- · Fast reverse recovery time.
- Low switching noise.
- High reliability due to highly reliable planar structure.
- Halogen free compliance.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		60	V
Nonrepetitive Peak Reverse Surge Voltage	V _{RSM}		66	V
Average Output Current	I0*2	50Hz resistive load, sine wave Tc=130°C	4	А
	Io*1	50Hz resistive load, sine wave Tc=83°C	8	А
Surge Forward Current	I _{FSM}	50Hz sine wave, 1 cycle	40	А
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

Note) *1. Indicates the total value

*2. Value per element

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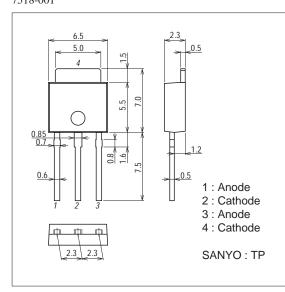
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Reverse Voltage	VR	I _R =1mA, Tj=25°C *2	60			V
Forward Voltage	VF	IF=3.0A, Tj=25°C *2			0.6	V
Reverse Current	IR	VR=30V, Tj=25°C *2			0.1	mA
Interterminal Capacitance	С	V _R =10V, Tj=25°C *2		130		рF
Transient Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC		6		°C/W

Note) *2. Value per element

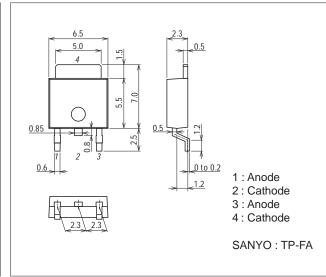
Package Dimensions

unit : mm (typ) 7518-001

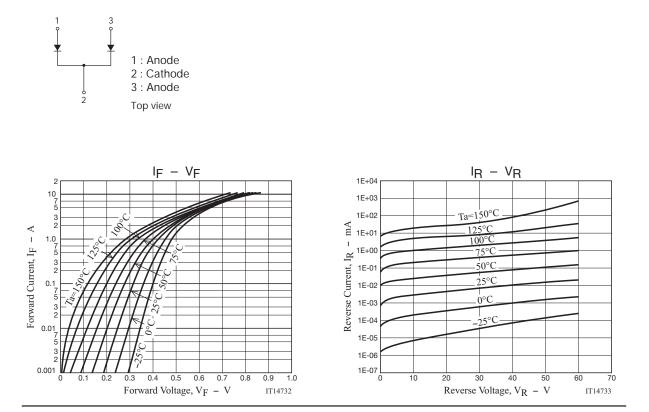


Package Dimensions

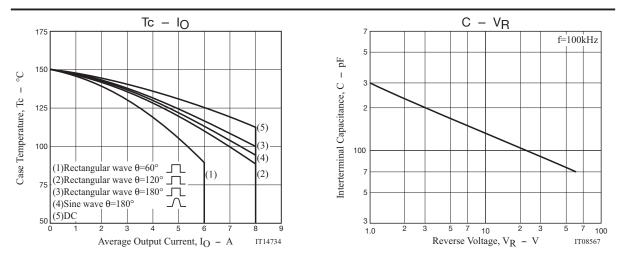
unit : mm (typ) 7003-002



Electrical Connection



SB80W06T



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